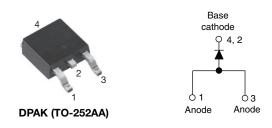
**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 3.5 A



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PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub> 3.5 A							
V <sub>R</sub>	100 V						
V <sub>F</sub> at I <sub>F</sub>	See Electrical table						
I <sub>RM</sub>	4.9 mA at 125 °C						
T <sub>J</sub> max.	150 °C						
E <sub>AS</sub>	5 mJ						
Package	DPAK (TO-252AA)						
Circuit configuration	Single						

## **FEATURES**

- · Low forward voltage drop
- Guard ring for enhanced ruggedness and long RoHS term reliability COMPLIANT HALOGEN
- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

## DESCRIPTION

The VS-30WQ10FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL CHARACTERISTICS VALU									
I <sub>F(AV)</sub>	Rectangular waveform	3.5	А						
V <sub>RRM</sub>		100	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	440	А						
V <sub>F</sub>	3 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.63	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS							
PARAMETER SYMBOL VS-30WQ10FN-M3 UI							
Maximum DC reverse voltage	V <sub>R</sub>	100	V				
Maximum working peak reverse voltage	V <sub>RWM</sub>	100					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C$ = 135 °C	3.5					
Maximum peak one cycle	I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load	440	A			
non-repetitive surge current See fig. 7		10 ms sine or 6 ms rect. pulse	condition and with rated V <sub>RRM</sub> applied	70				
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 10 mH	5.0	mJ				
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		0.5	А			

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FREE



ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum forward voltage drop See fig. 1		3 A	T.I = 25 °C	0.81				
	V <sub>FM</sub> <sup>(1)</sup>	6 A	1j=25 C	0.96	V			
	VFM \	3 A	T.I = 125 °C	0.63	V			
		6 A	1j=125 0	0.74				
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	1	mA			
See fig. 2		T <sub>J</sub> = 125 °C	VR = naleu VR	4.9				
Threshold voltage	V <sub>F(TO)</sub>			0.48	V			
Forward slope resistance	r <sub>t</sub>	ij = ij maximum	$T_J = T_J$ maximum		mΩ			
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	92	pF				
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm	5.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

<sup>(1)</sup> Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER SYMBOL TEST CONDITIONS VALUES								
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +150	°C				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	4.7	°C/W				
Approximate weight			0.3	g				
Approximate weight			0.01	oz.				
Marking device		Case style DPAK (TO-252AA)	30WQ10FN					

Note  $\frac{P_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink



# **VS-30WQ10FN-M3**

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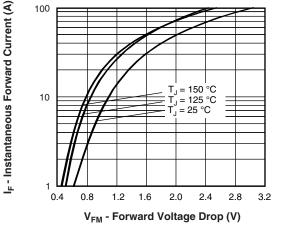
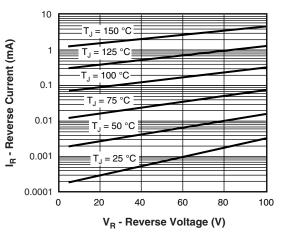
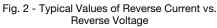


Fig. 1 - Maximum Forward Voltage Drop Characteristics





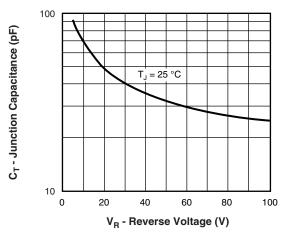
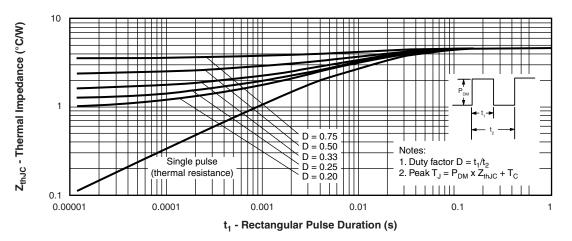


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

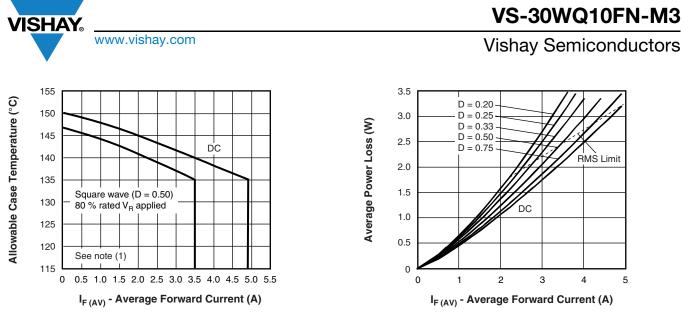


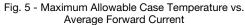


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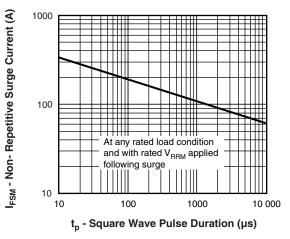


Fig. 7 - Maximum Non-Repetitive Surge Current

### Note

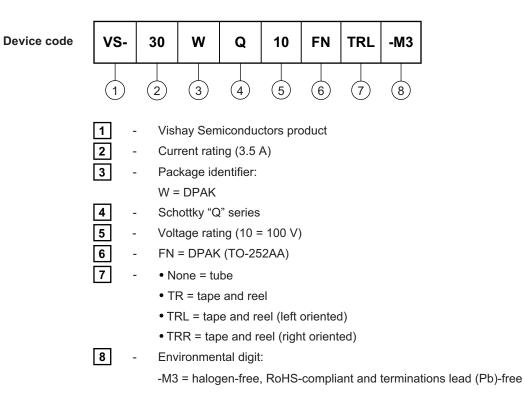
- (1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;
  - $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ x \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ x \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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**ORDERING INFORMATION TABLE** 

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ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-30WQ10FN-M3	75	3000	Antistatic plastic tube						
VS-30WQ10FNTR-M3	2000	2000	13" diameter reel						
VS-30WQ10FNTRL-M3	3000	3000	13" diameter reel						
VS-30WQ10FNTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?95627						
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95650						





D-PAK (TO-252AA) "M"

## **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		HES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

## Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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